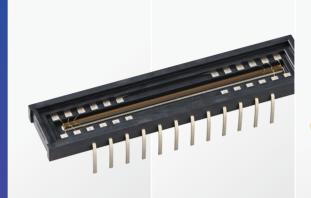
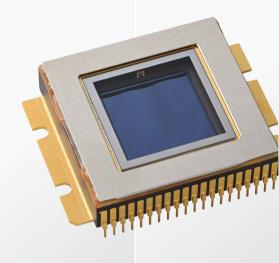
Image sensors for scientific measurements and industrial equipment

CCD/CMOS image sensors







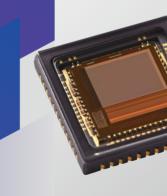








Image sensors

for scientific measurements and industrial equipment

Hamamatsu Photonics offers a wide lineup of image sensors for different wavelengths and applications. The CCD image sensors realize high quantum efficiency in the ultraviolet, visible, and near infrared regions. The CMOS image sensors realize low price, low power consumption, and compact size.

(VUV), soft X-rays, and hard X-rays.

Distance image sensor

CMOS

image sensor

InGaAs image sensor

Hamamatsu Photonics develops and manufactures image

sensors compatible with various spectral ranges such as

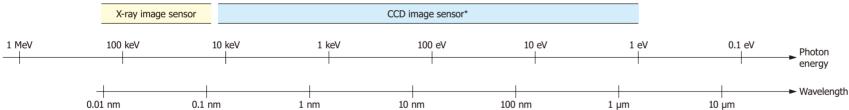
near infrared, visible light, ultraviolet, vacuum ultraviolet

Hamamatsu image sensors

Detectable energy and spectral response range

Wavelength [nm] =
$$\frac{1240}{\text{Photon energy [eV]}}$$

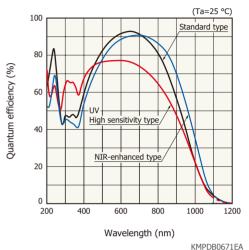




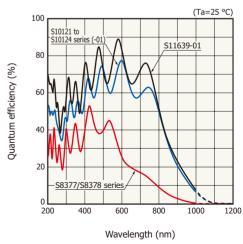
* No window for soft X-ray and hard X-ray

KMPDC1014EA

Spectral response (typical example, without window) [CCD image sensors]

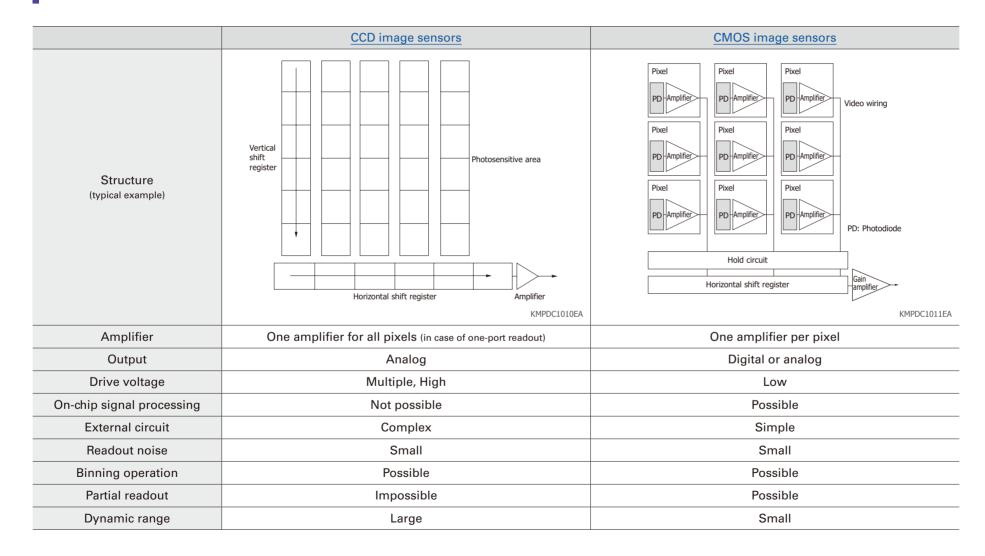


[CMOS image sensors]



KMPDB0681EA

Features of CCD/CMOS image sensors



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Image sensors
Image sensor

Back-thinned type

CCD image sensors

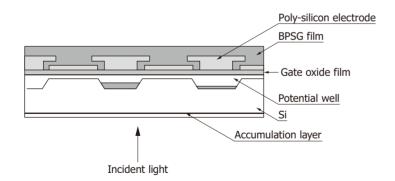
These realize high quantum efficiency in a wide spectral range.

The light incident surface of the front-illuminated CCD is formed on the surface of the silicon substrate on which the BPSG film, poly-silicon electrodes, gate oxide film, etc. are deposited, so incident light is mostly reflected or absorbed by that part. The quantum efficiency is therefore limited to approx. 40% at the highest in the visible region, and there is no sensitivity in the ultraviolet region.

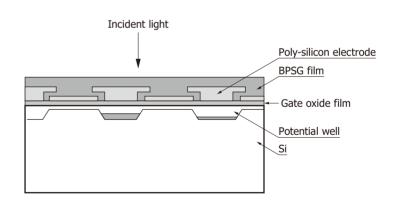
The back-thinned CCD also has BPSG film, poly-silicon electrodes, gate oxide film, etc. deposited on the surface of the silicon substrate. It achieves high quantum efficiency over a wide spectral range thanks to its structure, in which light is incident from the backside of the silicon substrate. Besides having high sensitivity and low noise which are the intrinsic features of CCDs, back-thinned CCDs are also sensitive to electron beams, soft X-rays, ultraviolet, visible, and near infrared region.

Cross section of CCD

[Back-thinned type]



[Front-illuminated type]



KMPDB0180EB KMPDB0179EB

Technology

Home Technology

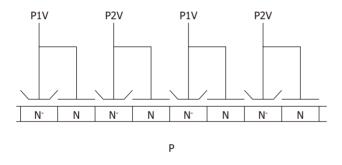
Home Technology CCD CMOS X-ray Related Technical image sensors image sensors image sensors image sensors products notes

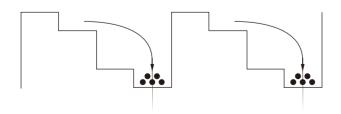
Resistive gate structure

CCD image sensors (built-in electronic shutter type)

Ordinary two-phase drive CCD

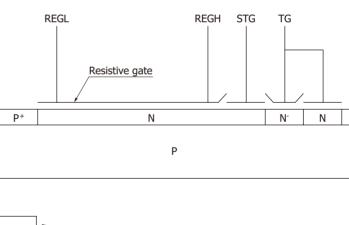
- · One pixel contains multiple electrodes and a signal charge is transferred by applying different clock pulses to those electrodes
- · No limit on pixel height and little image lag
- Schematic diagram and potential

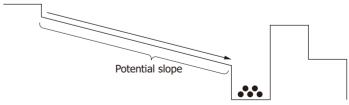




Resistive gate CCD

- ·Transfers signal charges by applying different voltages across the photosensitive area and forming a potential slope
- · Faster transfer is possible when pixel height is a few millimeters, compared to the case where a two-phase drive CCD undergoes line binning to be used as a 1-D sensor.
- Schematic diagram and potential





KMPDC0321EB

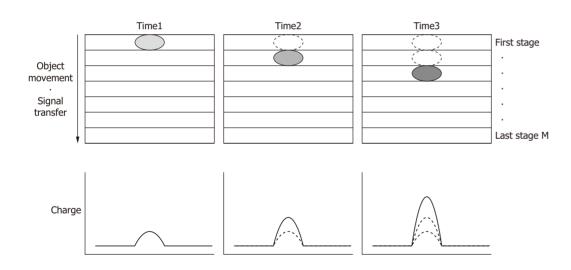
Lineup

TDI operation

TDI-CCD image sensors

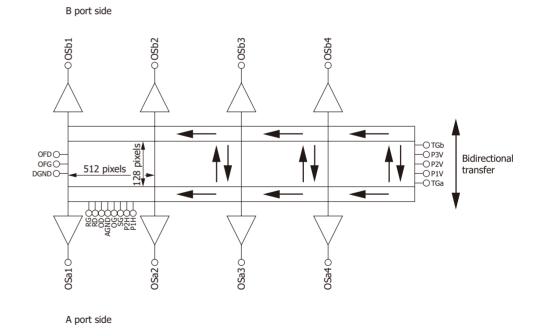
• Schematic diagram of integrated exposure in TDI operation

In FFT-CCD, signal charges in each column are vertically transferred during charge readout. TDI operation is a method that synchronizes the vertical transfer timing with the movement timing of the object incident on the CCD, so that signal charges are integrated a number of times equal to the number of vertical stages of the CCD pixels.



Sensor structure diagram (S10201-04-01)

By arranging multiple amplifiers and using multi-port output, we have made it capable of parallel image readout and achieved a high-speed line rate.



KMPDC0139EA KMPDC0260EA

Lineup

Technology

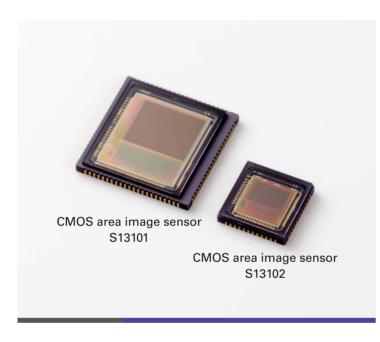
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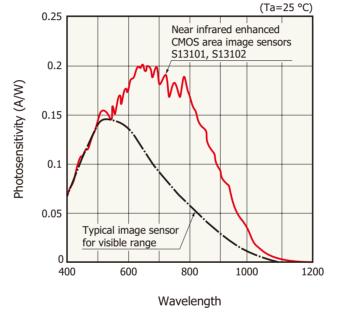
High near infrared sensitivity

CMOS image sensors

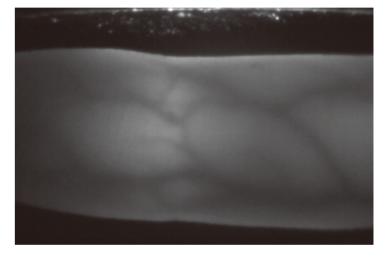
These CMOS image sensors have achieved high sensitivity in the near infrared region, using our unique photosensitive area technology.



• Spectral response (typical example)



 Imaging example of finger veins using near infrared enhanced CMOS area image sensor



KMPDB0489EA

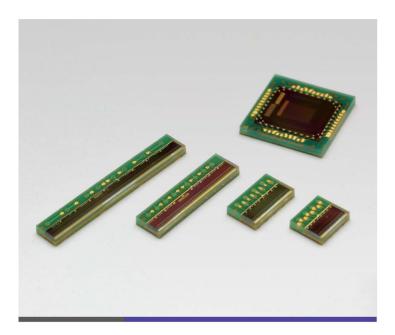
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Compact, thin COB package

CMOS image sensors

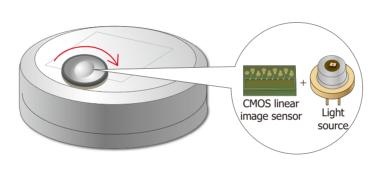


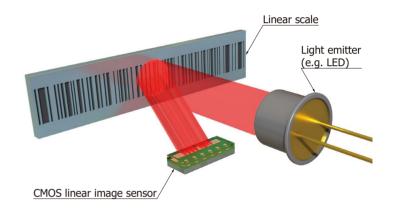
The CMOS image sensors in a compact, thin COB (chip on board) package contributes making equipment compact and low cost. They can be used in a wide range of applications, including barcode readers and encoders.

Application examples of CMOS linear image sensors

[Rangefinder (robot cleaner)]

[Encoder]





KMPDC0914EB KMPDC0913EA

Compact, thin COB package | Lineup | 9 / 46

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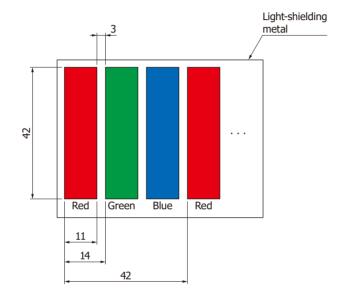
With color filters

CMOS linear image sensor

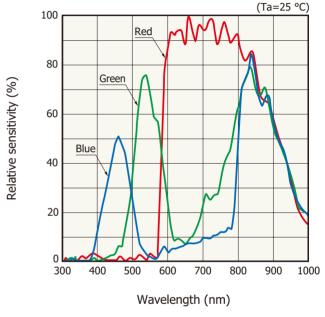
This type has color filters that transmit only light of a specific wavelength on the photodiode of the CMOS linear image sensor. It can acquire color information of the measurement target.



• Enlarged view of color filters (unit: μm)



Spectral response (typical example)



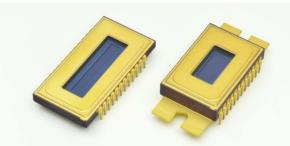
KMPDC0911EA KMPDB0483EB

With color filters S13488

CCD image sensors

Standard type

These products offer low noise, low dark current, and wide dynamic range, so they can detect very low-level light by lengthening the integration time.



High performance

▶ UV enhanced type

These CCDs exhibit high sensitivity in the UV region.

▶ Large full well type

The products realize a wide dynamic range.

▶ High-speed readout type

The products are capable of high-speed readout with built-in high-speed amplifier.

Highly functional

▶ Built-in electronic shutter type

Any integration timing can be set.

▶ NIR enhanced type

High sensitivity in the near infrared region of 800 nm or longer has been realized.

▶ High resolution type

The products are low noise CCDs with a small pixel size (12 \times 12 μ m).

▶TDI operation type

During high-speed imaging, the products can obtain high S/N images even under low-light-level conditions.

CCD image sensors

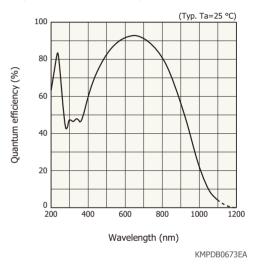
Home Technology | CCD | CMOS | X-ray | Related | Technical | Image sensors | Image sensors

Standard type

These offer low noise and low dark current, so they can detect very low-level light by lengthening the integration time. By doing binning operation (an operation which adds signals of pixels in the vertical direction), they can be used as a linear image sensor that is long in the vertical register direction, so they are suitable for detectors of spectrophotometers.

Type no.	Pixel size [µm (H) × µm (V)]	Number of effective pixels	Line rate* ¹ Frame rate* ²	Cooling* ³	Photo	Dedicated driver circuit (sold separately)
<u>\$7170-0909</u>		512 × 512	0.9 frames/s		WAXAAAAAA	<u>C7180</u>
<u>\$7030-0906</u>		512 × 58	418 lines/s			
<u>\$7030-0907</u>		512 × 122	316 lines/s	Non-cooled	***************************************	C7040
<u>\$7030-1006</u>		1024 × 58	213 lines/s			<u>C7040</u>
<u>\$7030-1007</u>		1024 × 122	160 lines/s		***************************************	
<u>S7171-0909-01</u>	24 × 24	512 × 512	0.9 frames/s			<u>C7181</u>
<u>\$7031-0906\$</u>		512 × 58	418 lines/s	-		
S7031-0907S		512 × 122	316 lines/s	One-stage	- Tunning	C7041
S7031-1006S		1024 × 58	213 lines/s	TE-cooled		<u>C7041</u>
<u>\$7031-1007\$</u>		1024 × 122	160 lines/s			
<u>\$12071</u> *4		1024 × 1024	Tap A: 0.1 frames/s Tap B: 1.5 frames/s			_

Spectral response (without window)



^{*1:} Full line binning (typ.) *2: Area scanning (typ.)

^{*3:} Two-stage TE-cooled type (S7032-1006/-1007) is available upon request (made-to-order products). *4: With anti-blooming function Note: Windowless types are also available.

CCD image sensors

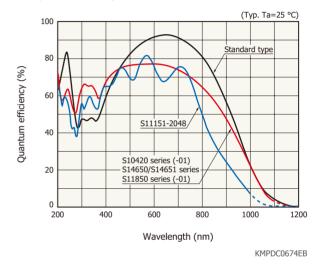
Home Technology | CCD | CMOS | X-ray | Related | Technical | February | Technical |

UV enhanced type

These CCDs exhibit high quantum efficiency in the UV region.

Type no.	Pixel size [µm (H) × µm (V)]	Number of effective pixels	Line rate* (lines/s)	Cooling	Photo	Dedicated driver circuit (sold separately)
<u>\$10420-1004-01</u>		1024 × 16	221			
<u>\$10420-1006-01</u>		1024 × 64	189		mmmm	
<u>\$10420-1104-01</u>		2048 × 16	116	Non-cooled		C11207.01
<u>\$10420-1106-01</u>		2048 × 64	106		<u>C11287-01</u>	
<u>\$14650-1024</u>	14 14	1024 × 192	95			
S14650-2048	14 × 14	2048 × 192	68			
S11850-1006-01		1024 × 64	189			
<u>\$11850-1106-01</u>		2048 × 64	106	One-stage	S5	044,000
S14651-1024		1024 × 192	95	TE-cooled	-	<u>C11860</u>
<u>\$14651-2048</u>		2048 × 192	68		-	
<u>S11151-2048</u>	14 × 200	2048 × 1	484	Non-cooled	22202 22222	<u>C11160</u>

Spectral response (without window)



Note: Windowless types are also available.

^{*} Full line binning (typ.)

CCD image sensors

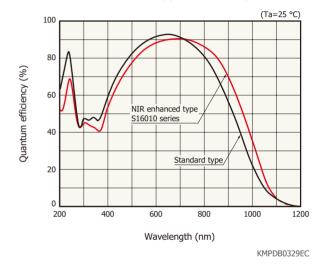
Home Technology | CCD | CMOS | X-ray | Related | Technical | February | Technical |

NIR enhanced type

These back-thinned CCDs exhibit high sensitivity in the near infrared region. They are used for Raman spectroscopy.

Type no.	Pixel size [μm (H) × μm (V)]	Number of effective pixels	Line rate*	Cooling	Photo	Dedicated driver circuit (sold separately)
S16000-1007 NEW	24 × 24	1024 122		Non-cooled	1111111111	<u>C7040</u>
S16001-1007S NEW	24 X 24	1024 × 122 160		One-stage TE-cooled	-	<u>C7041</u>
S16010-1006		1024 × 64	189	Non-cooled		011207.01
S16010-1106	14 14	2048 × 64	106	Non-cooled	()	<u>C11287-01</u>
<u>\$16011-1006</u>	14 × 14	1024 × 64	189	One-stage	2	041000
<u>\$16011-1106</u>		2048 × 64	106	TE-cooled		<u>C11860</u>

Spectral response (without window, typical example)



* Full line binning (typ.)

Note: Windowless types are also available.

CCD image sensors

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Large full well type

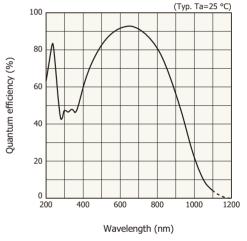
These have a wide dynamic range and are widely used for spectroscopic measurement.

Type no.	Pixel size	Number of effective pixels	Line rate*1	(k	capacity e ⁻) Horizontal* ²	Cooling	Photo	Dedicated driver circuit (sold separately)
<u>\$7033-0907</u>		512 × 122	316			Non-cooled		C7043
<u>\$7033-1007</u>	24 × 24	1024 × 122	160	320	3400	Non cooled	THE THE PARTY OF T	<u>C7043</u>
<u>\$7034-0907\$</u>		512 × 122	316		3400	One-stage		C7044
<u>\$7034-1007\$</u>		1024 × 122	160			TE-cooled		<u> </u>

^{*1:} Full line binning (typ.)

Note: Two-stage TE-cooled type (S7035 series), windowless type are also available.

Spectral response (without window)



KMPDB0673EA

^{*2:} Linearity=±1.5%

CCD image sensors

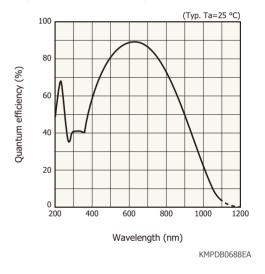
Home Technology | CCD CMOS X-ray Related Technical image sensors | Image se

High resolution type

These are low noise CCDs with a small pixel size (12 \times 12 μ m).

Type no.	Pixel size [μm (H) × μm (V)]	Number of effective pixels	Line rate*1 (lines/s)	Cooling* ²	Photo	Dedicated driver circuit (sold separately)
<u>\$10140-1107-01</u>		2048 × 122	107			
<u>\$10140-1108-01</u>		2048 × 250	80	Non-cooled	TANAMANAN	<u>C10150-01</u>
<u>\$10140-1109-01</u>		2048 × 506	40			
S10141-1107S-01	12 × 12	2048 × 122	107			
S10141-1108S-01		2048 × 250	80	One-stage		<u>C10151-01</u>
S10141-1109S-01		2048 × 506	40	TE-cooled		
<u>\$12101</u> *3		2048 × 2048	Tap A: 0.02 frames/s Tap B: 2.4 frames/s			_

Spectral response (without window)



Note: Windowless types are also available.

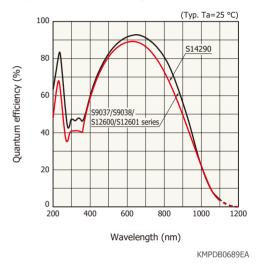
^{*1:} Full line binning (typ.)

^{*2:} Note:Two-stageTE-cooled type [S10142 series (-01)] is available upon request (made-to-order products).

^{*3:} With anti-blooming function

Type no.	Pixel size [μm (H) × μm (V)]	Number of effective pixels	Data rate (MHz)	Line rate* (lines/s)	Cooling	Photo
S9037-0902		512 × 4		16300	Non-cooled	***************************************
S9037-1002		1024 × 4	10	8100	Non-cooled	
S9038-0902S		512 × 4	_	16300	One-stage TE-cooled	
S9038-1002S	24 × 24	1024 × 4		8100		
<u>S12600-1006</u>	24 / 24	1024 × 58		2097	- Non-cooled	
<u>S12600-1007</u>		1024 × 122		1162		· · · · · · · · · · · · · · · · · · ·
S12601-1006S		1024 × 58	5	2097	One-stage	
S12601-1007S		1024 × 122		1162	TE-cooled	
<u>S14290</u>	24 × 500	1024 × 1		10000	Non-cooled	

Spectral response (without window)



* Full line binning (typ.)

Note: Windowless types are also available.

High resolution

High-speed readout type

These CCDs have a small pixel size and a data rate of 10 MHz.

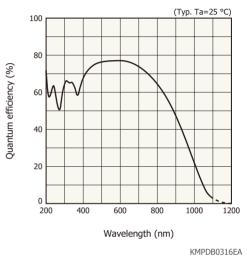
Туре по.	Pixel size [µm (H) × µm (V)]	Number of effective pixels	Data rate	Line rate*	Number of ports	Cooling	Photo	Dedicated driver circuit (sold separately)
<u>S11071-1004</u>		1024 × 16	1024 × 16	1777				
<u>\$11071-1006</u>		1024 × 64		751			7,1,1,1,1,1,1,1,1	C11200 01
S11071-1104		2048 × 16 1303		Non-cooled		<u>C11288-01</u>		
<u>\$11071-1106</u>		2048 × 64	3 × 64 × 192	651			(**************************************	
<u>S11851-1106-01</u>	14 × 14	2048 × 64		651		One-stage TE-cooled		_
S14660-1024		1024 × 192		296	1	Non-cooled		C11288-01
<u>\$14660-2048</u>		2048 × 192		148	- 1	Non-cooled	•	<u>C11200-01</u>
<u>\$14661-1024</u>		1024 × 192		296		One-stage TE-cooled		
S14661-2048		2048 × 192		148		One-stage TE-cooled		_
S13240-1107		2048 × 122	2048 × 122	921				
S13240-1108	12 × 12 2048 × 250	539		Non-cooled	***************************************	_		
S13240-1109		2048 × 506 203						

^{*} Full line binning (typ.)

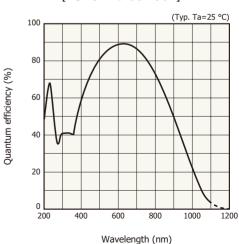
Note: Windowless types are also available.

Spectral response (without window)

S11071/S11851/S14660/S14661 series]



[S13240 series]



KMPDB0688EA

High resolution

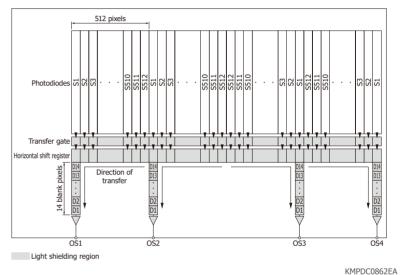
High-speed readout type

These CCDs have a small pixel pitch. The S12379 and S15729-01 realize high-speed line rate with multi-port readout.

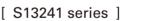
Type no.	Pixel size [µm (H) × µm (V)]	Number of effective pixels	Data rate	Line rate	Number of ports	Cooling	Photo	Dedicated driver circuit (sold separately)
S13241-1107S		2048 × 122	10	921* ¹				
<u>\$13241-1108\$</u>	12 × 12	2048 × 250		539* ¹	1	One-stage TE-cooled	-	_
S13241-1109S		2048 × 506		203*1				
<u>S12551-1024</u>	- 14 × 14	1024 × 1		37900*2				-
<u>S12551-2048</u>	14 X 14	2048 × 1	40	19200*2	1	Non-cooled	520101 201010	-
<u>S12379</u>	8 × 8	2048 × 1	048 × 1 72000	72000	4	TVOII-COOIGU		
<u>S15729-01</u>	10 × 180	2048 × 1		70000	4		***************************************	C15821-2351

^{*1:} Full line binning (typ.)

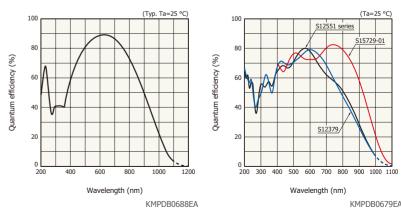
Device structure (schematic of CCD chip as viewed from top of dimensional outline) [S15729-01 (4 ports)]



Spectral response (without window)



[S12551 series, S12379, S15729-01]



^{*2:} With electronic shutter (line rate when electronic shutter is not used) Note: Windowless types are also available.

CCD **CMOS** X-ray Related Technical CCD image sensors Home Technology image sensors image sensors image sensors products notes

Built-in electronic shutter type

These are CCD linear image sensors for spectrophotometry with a built-in electronic shutter function. High-speed transfer is enabled by adopting a resistive gate structure (except for S15351-2048).

Type no.	Pixel size	Number of effective pixels	Line rate	Cooling	Photo	Dedicated driver circuit (sold separately)
<u>S11155-2048-02</u>	14 × 500			Non-cooled		C11165-02
<u>S11156-2048-02</u>	14 × 1000		2327 2048 × 1	Non cooled	THO MINE	<u>C11105-02</u>
S13255-2048-02	14 × 500			One-stage TE-cooled		
S13256-2048-02	14 × 1000	2048 × 1			711111111111111111111111111111111111111	_
<u>\$15254-2048</u>	14 × 200		2356			C15361-2105
<u>S15257-2048</u>	14 × 2500		2294	Non-cooled		<u>C13301-2103</u>
<u>\$15351-2048</u>	14 × 200		1180		***************************************	<u>C15361-1105</u>

Note: Windowless types are also available.

Related products



CMOS linear image sensors for spectrophotometry

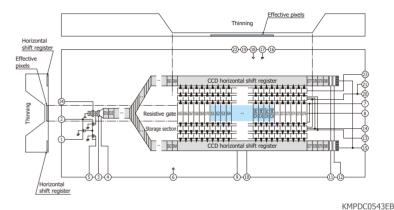
High sensitivity type



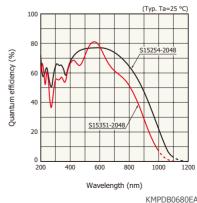
CMOS linear image sensors for industrial equipment

High sensitivity type

Device structure (schematic of CCD chip as viewed from top of dimensional outline) S11155/S11156/S13255/S13256-2048-02, S15254/S15257-2048]



 Spectral response (without window) S15254-2048, S15351-2048



CCD image sensors

Home Technology | CCD | CMOS | X-ray | Related | Technical | Image sensors | Image sensors

TDI-CCD image sensors

High S/N images can be obtained when moving objects are subjected to integration while being exposed to light during high-speed imaging. The S14810 and S14813 have a hybrid structure combining TDI-CCD and CMOS readout circuit. With the photosensitive area technology that Hamamatsu has cultivated over many years, the S14813 realizes the highest level of UV sensitivity and UV resistance in the world.

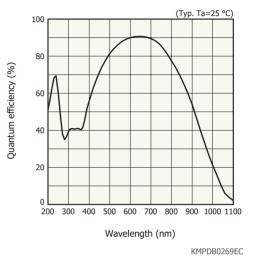
Type no.	Pixel size [μm (H) × μm (V)]	Number of effective pixels	Number of ports	Pixel rate (MHz/port)	Line rate	Vertical transfer	Photo	Applicable camera (sold separately)
<u>\$10200-02-01</u>		1024 × 128	2			Bidirectional		_
<u>\$10201-04-01</u>		2048 × 128	4	30	50000			C10000-801* C10000-A01*
<u>\$10202-08-01</u>	12 × 12	4096 × 128	8	30				_
<u>\$10202-16-01</u>	12 × 12	4096 × 128	16		100000			_
<u>\$14810</u>	102	1024 120		0.1	100000			
<u>S14813</u>		1024 × 128	1024	0.1	100000			_

^{*}The C10000 series camera is a product of Hamamatsu's System Division.

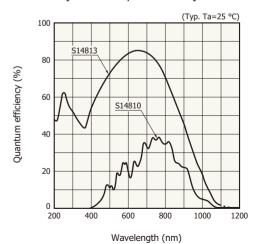
Note: TDI: time delay integration

Spectral response

[S10200/S10201/S10202 series]



[S14810, S14813]



KMPDB0580EA

CMOS image sensors

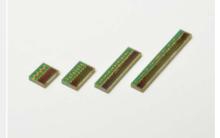
CMOS linear image sensors for spectrophotometry

These have vertically long pixels, realizing high quantum efficiency in the ultraviolet to visible regions.



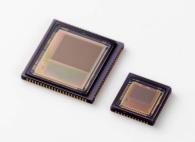
CMOS linear image sensors for industrial equipment

We offer sensors suitable for position detection, encoders, line scan cameras, and more. These are equipped with a timing generator and signal processing amplifier, and are driven by a simple input pulse and a single power supply.



CMOS area image sensors

We offer a type that has high sensitivity in the UV and near IR region.



Highly functional CMOS image sensors

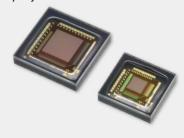
▶ Distance image sensors

These sensors measure the distance to an object by TOF (time-of-flight) method. When used in combination with a pulse modulated light source, these sensors output phase difference information on the timing that the light is emitted and received.



▶ Profile sensors

These high-performance sensors are specialized for acquiring 2D projection data.



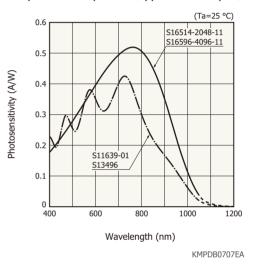
For spectrophotometry

High sensitivity type

These are high sensitivity CMOS linear image sensors employing a photosensitive area with vertically long pixels. High sensitivity and high durability have been achieved even in the ultraviolet region. The S16514-2048-11 and S16596-4096-11 realize high sensitivity in near IR region and smooth spectral response.

Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo	Dedicated driver circuit (sold separately)
<u>\$16528-1024-11</u>		28	1024	8960	61	<u>C13015-01</u>
S11639-01*1			2048	4672	[58	C1201E 01
S15739-1024*2		14	1024	8960		<u>C13015-01</u>
<u>S13014</u> *2		14	512	16556	,,,,,	040045 04*3
<u>\$14739-20</u>	000		256	28735		C13015-01*3
S13496*1	200		4096	2387		<u>C13015-01</u>
S15796-2048*2		7	2048	4672		C13015-01
S15796-1024*2			1024	8960	***************************************	C13015-01*3
<u>\$16514-2048-11</u>		14	2048	4672		<u>C13015-01</u>
S16596-4096-11		7	4096	2387		

Spectral response (typical example)



Related products



CCD image sensors

Built-in electronic shutter type

^{*1:} We also offer types with light-shielding pixels (S11639-11, S13496-11). *2: Surface mount type is also available. *3: A conversion board is required during use.

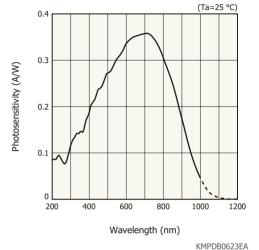
For spectrophotometry

Large saturation charge type

This current output type features high UV sensitivity and smooth spectral response. It has a large saturation charge and integration time is variable for each pixel, so it can efficiently detect the dispersed very low-level light.

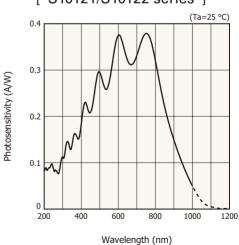
Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo	Dedicated driver circuit (sold separately)
<u>\$10121-128Q-01</u>			128	1923	:	
S10121-256Q-01	2.5		256	969		
S10121-512Q-01		F0	512	486		C10808
S10122-128Q-01		50	128	3846		series
S10122-256Q-01	0.5		256	1938	. [
S10122-512Q-01			512	972		
<u>\$15908-512Q</u>	2.5	50	512	486	1	C10808
<u>\$15909-1024Q</u>	2.5	25	1024	243	<u> mmm</u>	series

Spectral response (typical example) [\$15908-512Q, \$15909-1024Q]



....

[S10121/S10122 series]



KMPDB0442EA

CMOS linear image sensors

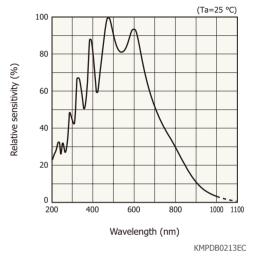
Home Technology | CCD | CMOS | X-ray | Related | Technology | Image sensors | Image

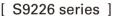
For spectrophotometry

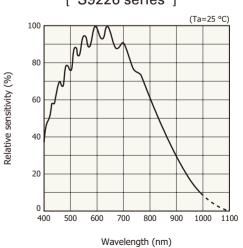
These linear image sensors have a built-in readout circuit.

Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo
<u>\$8377-1280</u>			128	3846	WW.
<u>\$8377-2560</u>		50	256	1938	TYYY
<u>\$8377-5120</u>	500		512	972	TTTT III
S8378-256Q	500		256	1938	Is—al
S8378-512Q		25	512	972	TYYY
S8378-1024Q			1024	487	TTTT I
<u>S9226-03</u>	105	70	1024	104	
<u>\$9226-04</u>	125	7.8	1024	194	

Spectral response (typical example, without window)[S8377/S8378 series]







KMPDB0229EC

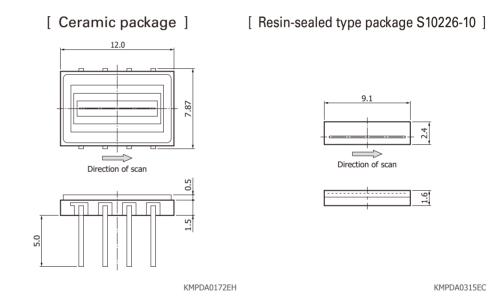
Resin-sealed type package

These are a compact and surface mounted high-volume production type.

Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo
<u>\$10226-10</u>	125	7.8	1024	194	
<u>\$10227-10</u>	250	12.5	512	9434	
<u>S11106-10</u>	63.5	63.5	128	67568	
<u>S11107-10</u>	127	127	64	119048	
<u>S12443</u>	125	7	2496	3924	
<u>\$13131-512</u>			512	3787	0.010.01
<u>\$13131-736</u>	62.5	5.5	736	2659	*arajara
<u>S13131-1536</u>	63.5		1536	1288	
<u>\$13434-2496</u>		5.25	2496	796	

• Size of ceramic package and resin-sealed type package

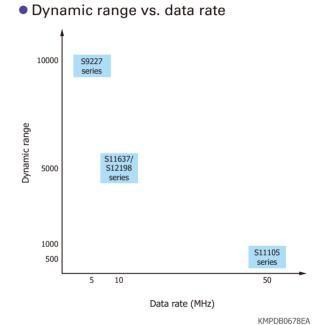
The following products have the same photosensitive area size (7.9872 \times 0.125 mm), but the resin-sealed type package is more compact and thin.



High-speed readout type

These CMOS image sensors are capable of high-speed readout.

Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo
<u>\$9227-03</u>	250	12.5	512	9434	TITT
<u>\$9227-04</u>	250	12.0	312	3404	
<u>S11105</u>	250	12.5	512	88652	
<u>S11105-01</u>	200	12.0		88495	
<u>S11637-10240</u>	500	12.5	1024	9487	
S11637-2048Q	333	.2.0	2048	4812	
S12198-512Q-01	500	25	512	18450	
S12198-1024Q-01	330	25	1024	9487	



High-speed readout type

These CMOS image sensors are capable of high-speed readout.

Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo
<u>\$14416-02</u>			256	36231	
<u>\$14416-06</u>	63.5	63.5	768	12690	•
<u>\$14416-12</u>			1536	6426	- T 1-
<u>\$14417-02</u>	407	407	128	67567	
<u>\$14417-06</u>	127	127	384	24752	2

S14416 series

The S14416-02/-06/-12 are products with 128-element photodiode arrays arranged in 2/6/12 parts respectively. Select a product of the size that matches your detection target.

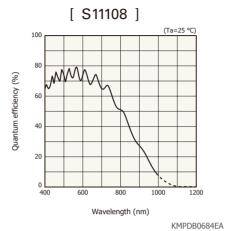


High sensitivity type

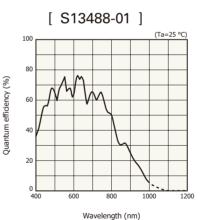
We have realized high sensitivity by incorporating an amplifier for each pixel.

Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo	Dedicated driver circuit (sold separately)
<u>S11108</u>	14	14	2048	4672		_
<u>\$12706</u>	7	7	4096	2387		C13015-01
<u>\$13488-01</u>	42	14	2048	4672		-
<u>S13828</u>	84	28	1024	8960		C13015-01

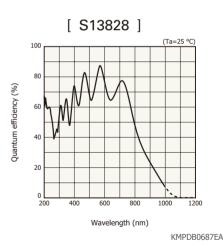
Spectral response (typical example, without window)







KMPDB0686EA



Related product



CCD image sensors

Built-in electronic shutter type

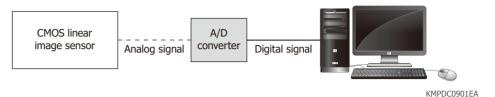
Digital output type

These are linear image sensors with a built-in A/D converter. The S15611-10 realizes smooth spectral response.

Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo
<u>S10077</u>	50	14	1024	972	[
<u>S11720-20</u>	107	407	1536	45400	***
<u>S11720-40</u>	127	127	3072	45400	BOARD AND AND AND AND AND AND AND AND AND AN
<u>S13774</u>	7	7	4096	100000 (high-speed mode)	
<u>S14772</u>	14	14	2048	125000 (high-speed mode)	
<u>S15611</u>	000	7	1004	04000	
S15611-10 (NEW)	200	/	1024	34000	
<u>S15778</u>	7	7	8192	100000 (high-speed mode)	
S16074* NEW	7 9.3 14	7 9.3 14	4160 3120 2080	35000 46000 65000	

^{* 3} lines of pixel sizes (7 \times 7 μ m, 9.3 \times 9.3 μ m, 14 \times 14 μ m) are arranged in parallel in the photosensitive area and can be switched with SPI settings.

A/D conversion of CMOS linear image sensors [Analog output type]

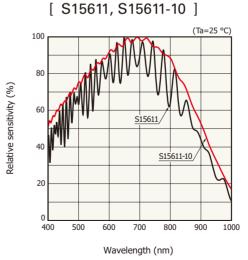


[With A/D converter (digital output type)]



KMPDC0902EA

• Spectral response (typical example)



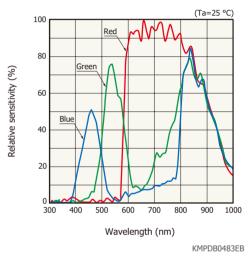
KMPDB0712EA

With RGB color filters

This CMOS linear image sensor has sensitivity to red (630 nm), green (540 nm), and blue (460 nm) light. Each pixel has a filter in the order RGB, so it can obtain the color information of the measurement target.

Type no.	Pixel height	Pixel pitch	Number of pixels	Line rate max. (lines/s)	Photo
<u>\$13488</u>	42	14	2048	4672	

Spectral response (typical example)



Note: This sensor also has sensitivity in the infrared region, so cut off incident infrared light as needed.

With color filters

S13488

These APS (active pixel sensor) type CMOS area image sensors have high sensitivity in the UV and near infrared light. They integrate a timing generator, bias generator, amplifier, A/D converter, and are easy to handle because of all-digital I/O.

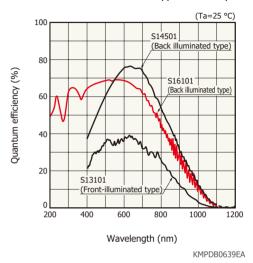
Technology

image sensors

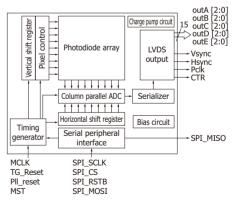
Home

Type no.	Pixel size	Number of effective pixels	Spectral response range (nm)	Frame rate max. (frames/s)	Туре	Photo
S16101 NEW	74 × 74	1280 × 1024	200 to 1100	146	Back-illuminated type	
<u>S14501</u>	7.4 × 7.4	7.4 × 7.4		400 to 1100		
<u>S13101</u>	7.4 × 7.4	1280 × 1024		146		
<u>\$13102</u>	7.4 × 7.4	640 × 480	400 to 1100	78	- Front-illuminated type	
<u>S13499</u>	9.9 × 9.9	659 × 494	400 to 1100	75	Pront-munimated type	
<u>S14250</u>	50 × 50	30 × 30		344		

Spectral response (S16101, S14501, S13101, typical example)



Block diagram (S16101, S14501, S13101)



KMPDC0529EC

Distance image sensors

Home Technology | CCD | CMOS | X-ray | Related | Technology | Image sensors | Image se

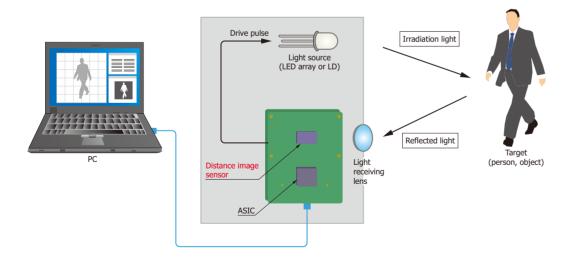
Distance linear image sensors

The distance image sensors are designed to measure the distance to an object by TOF method. When used in combination with a pulse modulated light source, these sensors output phase difference information on the timing that the light is emitted and received. Distance data can be obtained by performing calculation on the signals with an external signal processing circuit or a PC.

Type no.	Pixel height	Pixel pitch	Number of effective pixels	Video data rate max. (MHz)	Photo
<u>\$15452-01WT</u>	50	20	64	E	
S15453-01WT	50	20	256	5	

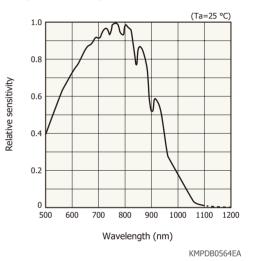
Note: An evaluation kit is available. Contact us for detailed information.

Configuration example of distance measurement



KMPDC0417EE

Spectral response



Linear image sensors Area image sensors ASIC

CMOS X-ray Technical Related Distance image sensors Home Technology image sensors image sensors image sensors products notes

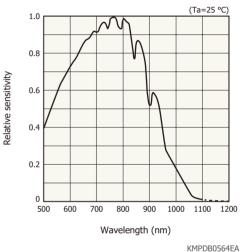
Distance area image sensors

The distance image sensors are designed to measure the distance to an object by TOF method. When used in combination with a pulse modulated light source, these sensors output phase difference information on the timing that the light is emitted and received. Distance data can be obtained by performing calculation on the signals with an external signal processing circuit or a PC.

Type no.	Pixel size [μm (H) × μm (V)]	Pixel pitch	Number of effective pixels	Video data rate max. (MHz)	Photo
<u>\$15454-01WT</u>	50 × 50	50	96 × 72	10	
S16443-01WT	20 × 50	20 (H) × 201.5 (V)	128 × 8	10	
S16444-01WT	20 × 50	20 (H) × 201.5 (V)	320 × 20	10	

Note: An evaluation kit is available. Contact us for detailed information.

Spectral response



ASIC Linear image sensors Area image sensors 34 / 46 Distance image sensors

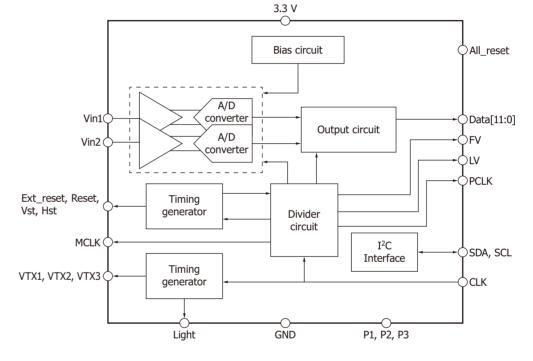
Home Technology | CCD | CMOS | X-ray | Related | Technical | mage sensors | image sensors | image sensors | image sensors | products | notes |

ASIC for distance image sensor

The peripheral circuits required for driving and signal processing of the distance image sensors are integrated into the ASIC.



Block diagram



SDA: serial data SCL: serial clock

KACCC1053EA

Linear image sensors Area image sensors ASIC

CMOS image sensors

Home Technology | CCD | CMOS | X-ray | Related | Technology | Image sensors | Image sensor

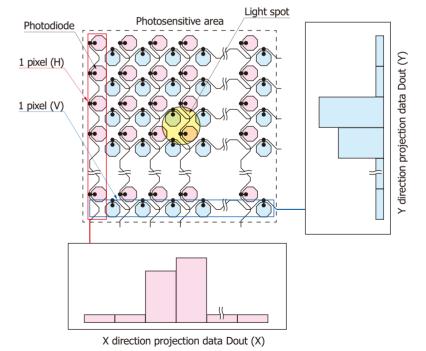
Profile sensors

These high-speed frame rate CMOS image sensors are specialized for acquiring 2-D projection data. It is possible to detect multiple light spots simultaneously. The S15366 series integrate the center-of-gravity calculation circuit and they can directly output the center-of-gravity position coordinates.

Type no.	Number of lines (X/Y directions)	Pixel pitch	Frame rate 8-bit max. (frames/s)	Photosensitive area [mm (H) × mm (V)]	Photo
<u>S9132</u>	256		3200	1.9968 × 1.9968	
S15366-256	250	7.8	3156	1.9908 × 1.9908	
<u>S15366-512</u>	512		1602	3.9936 × 3.9936	

Operating principle

In the photosensitive area arranged two-dimensionally, the photosensitive area for the X-direction projection data is connected in one vertical column, and the photosensitive area for the Y-direction projection data is connected in one horizontal row using metal wiring. Output of the photosensitive area of the same line is read out as added data, making it possible to acquire projection data in the X/Y directions. The amount of data per frame is small, achieving a high frame rate.



X-ray image sensors

For radiography

These large area, high resolution CMOS area image sensors are used in X-ray radiography equipment.



TDI-CCD area image sensors

TDI operation enables X-ray imaging of large subjects. They can be used for X-ray radiography equipment, and for industrial in-line non-destructive inspection.



For non-destructive inspection

► CMOS area image sensors

These CMOS image sensors can be connected to a PC via USB. They have a thicker FOP, realizing high radiation resistance.



▶ Photodiode arrays with amplifier

The products can be used for in-line industrial product inspection equipment, foreign matter inspection equipment, etc. for canned and retort foods.



For radiography

CMOS area image sensors

These are large area, high resolution CMOS area image sensors.

We have a type with FOP (fiber optic plate) input window and a type with a cable to be used for simple X-ray imaging. They have LDVS digital output with a built-in 14-bit A/D converter.

Type no.	Scintillator	Pixel size [µm (H) × µm (V)]	Number of effective pixels	Frame rate* (frames/s)	Photo
<u>\$10830-12</u>	Csl				
<u>\$10834-12</u>	CsI (+ FOP)	20 × 20	1000 × 1500	0.9	Q.
<u>S10831</u>	Csl	20 × 20	1300 × 1700	0.6	
<u>\$10835-12</u>	(+ FOP)	23 % 20	.555 % 1760	5.10	Q.

^{*} Global clock=20 MHz

Note: Please prepare a circuit for driving the sensor.



For non-destructive inspection

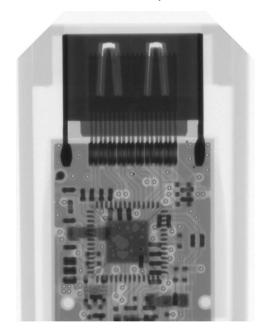
CMOS area image sensors

This product has an APS type CMOS area image sensor and USB interface, built into a compact housing. The fiber optic plate (FOP) protects the X-ray image sensor to realize 1 million Gy* of radiation resistance.

Type no.	Scintillator	Pixel size [µm (H) × µm (V)]	Number of effective pixels	Frame rate (frames/s)	Photo
<u>S15683-13</u>	CsI (+ FOP)	20 × 20	1300 × 1700	0.46	19

^{*} X-ray tube voltage=60 kV, without Al filter

X-ray imaging example[Electronic part]



For non-destructive inspection

Photodiode arrays with amplifier

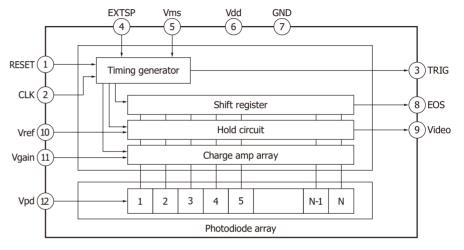
Type no.	Pixel height	Pixel pitch	Number of pixels	Drive voltage (V)	Line rate (lines/s)	Charge amplifier feedback capacitance* (pF)	Photo	Dedicated driver circuit (sold separately)
<u>S11865-64G</u>	0.8	0.8	64	5	14678	0.5		C0440 04
S11865-128G	0.6	0.4	128	5	7568	0.5	•	<u>C9118-01</u>
S13885-128G	0.6	0.4	128	3.3	7568	0.125		
S11865-256G	0.3	0.2	256	5	3844	0.5		_
S13885-256G	0.3	0.2	256	3.3	3844	0.125		
S11866-64G-02	1.6	1.6	64	5	14678	0.5	and the same of th	C0110 01
S11866-128G-02	0.8	0.8	128	5	7568	0.5	• •	<u>C9118-01</u>
S13886-128G	0.8	0.8	128	3.3	7568	0.125		-

^{*} High gain

Note: We also offer a type without a phosphor sheet.

The photodiode arrays with an amplifier consist of a Si photodiode array and a CMOS signal processing IC chip. A phosphor sheet is attached to the photosensitive area, making it suitable for non-destructive inspection.

• Block diagram (S11865-64G/-128G, S11866-64G-02/-128G-02)



KMPDC0153EA

Driver circuit C9118-01

This CMOS driver circuit is designed for the photodiode arrays with amplifier S11865/S11866 series. It is possible to configure a long and narrow image sensor by combining this product with a compatible photodiode array with amplifier (sold separately) and arranging multiple combinations in line. It operates with two signal inputs, MCLK and M-RESET, and a single +5 V power supply.



X-ray image sensors

Home Technology | CCD CMOS X-ray | Related Technical | image sensors | image sensors | image sensors | image sensors | products | notes |

TDI-CCD area image sensors

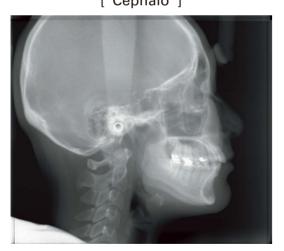
These are long and narrow type CCDs coupled with FOS.

They are used for X-ray radiography and non-destructive X-ray inspection, etc.

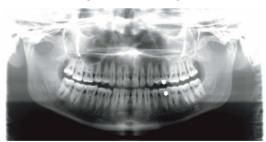
Type no.	Scintillator	Pixel size [[pm (H) × pm (V)]	Number of effective pixels	Line rate*1 max. (lines/s)	Photo
<u>S7199-01</u> * ²	Csl	48 × 48	1536 × 128 (× 2-chip buttable)	2100	
S8658-01*2	(+ FOP)		1536 × 128 (× 3-chip buttable)		

^{*1:} TDI scanning

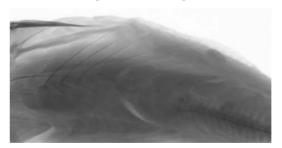
X-ray imaging examples[Cephalo]



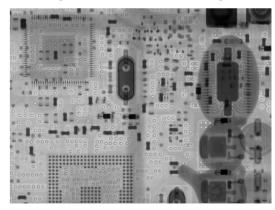
[Panorama]



[Fish bone]



Printed circuit board]



^{*2:} We also offer types (S7199-01F, S8658-01F) that have no scintillator, with only the FOP coupled.

Related products

Technology

CMOS image sensors

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CCD multichannel detector heads

These products have a housing with a built-in driver circuit for a back-thinned CCD (sold separately) with a care of heat dissipation.



Type no.	Output	Cooling	Applicable sensors (sold separately)
<u>C7040</u>		Non-cooled	S7030 series, S16000-1007
<u>C7041</u>		One-stage TE-cooled	S7031 series, S16001-1007S
<u>C7043</u>		Non-cooled	S7033 series
<u>C7044</u>	Analog	One-stage TE-cooled	S7034 series
<u>C7180</u>		Non-cooled	S7170-0909
<u>C7181</u>		One-stage TE-cooled	S7171-0909-01
C10150-01		Non-cooled	S10140 series (-01)
<u>C10151-01</u>		One-stage TE-cooled	S10141 series (-01)

Note: A multichannel detector head for the two-stage TE-cooled type CCD area image sensors (back-thinned type) S7032 series is also available.

Multichannel detector head controller C7557-01

This controller was developed for basic operation of multichannel photometry. By connecting it to a Hamamatsu multichannel detector head and a PC, it allows easy control of the detector head and data acquisition with the use of dedicated software that comes with the unit.



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for CCD image sensors

CCD image sensors can be evaluated by using these low-price driver circuits.



Type no.	Interface	max. (lines/s)	Applicable sensors (sold separately)
<u>C11160</u>		483	S11151-2048
		210	S10420-1004-01
		180	S10420-1006-01, S16010-1006
C11007 01		110	S10420-1104-01
<u>C11287-01</u>		100	S10420-1106-01, S16010-1106
		90	S14650-1024
		70	S14650-2048
		1420	S11071-1004
	USB 2.0	1040	S11071-1104
C11200 01		600	S11071-1006
<u>C11288-01</u>		520	S11071-1106
		290	S14660-1024
		150	S14660-2048
C11165-02		2780	S11155-2048-02, S11156-2048-02
		126	S11850-1006-01, S16011-1106
C11000		100	S14651-1024
<u>C11860</u>		83	S11850-1106-01, S16011-1106
		71	S14651-2048
C15361-1105		2340	S15351-2048
<u>C15361-2105</u>	USB 3.1 Gen1	2340	S15254-2048
		1870	S15257-2048

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CCD image sensors

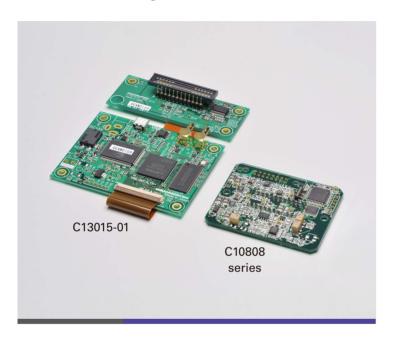
CMOS image sensors

X-ray image sensors

Driver circuits

for CMOS image sensors

CMOS image sensors can be evaluated by using these low-price driver circuits.



Type no.	Features	Applicable sensors (sold separately)	
C10808 series	High-speed readout type (C10808) and low-noise type (C10808-01), both equipped with integration time function	S10121 to S10124-01 series, S15908-512Q, S15909-1024Q	
C13015-01	Built-in 16-bit A/D converter, interface: USB 2.0, single power supply operation: USB bus powered (+5 V)	S11639-01, S12706, S13496, S16528-1024-11, S16514-2048-11, S16596-4096-11, S15796 series, S15739-1024, S13014, S14739-20, S13828	

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Image sensor module

This module for OCT has a built-in CCD image sensor.

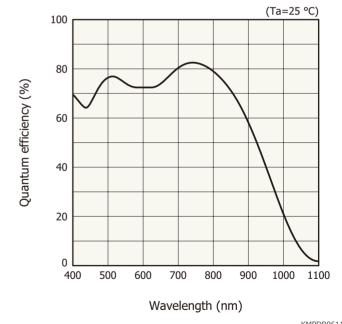


Type no.	Line rate max. (lines/s)	Interface	Built-in sensor
C15821-2351	70000	CameraLink	S15729-01

Features

- · High-speed line rate: 70000 lines/s
- · Number of pixels: 2048 pixels (512 pixels × 4 taps)
- · Single 12 V power supply operation
- · High near infrared sensitivity (>60%, λ =850 nm)
- · CameraLink interface
- · Flat field correction function
- · External input synchronization mode
- · With evaluation software

Spectral response (typical example)



KMPDB0611EA

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Resin-sealed CMOS linear image sensors

Inquiries from online

www.hamamatsu.com

- Information described in this material is current as of May 2023.
- Product specifications are subject to change without prior notice due to improvements or other reasons. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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KMPD0002E28 May 2023 DN

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